

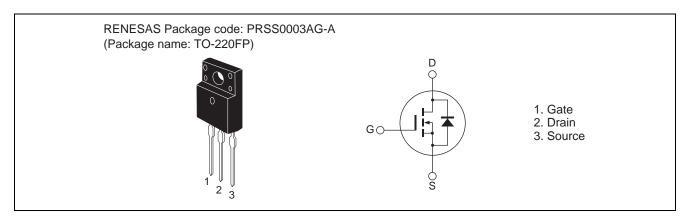
RJK5012DPP-E0

500V - 12A - MOS FET High Speed Power Switching R07DS0561EJ0100 Rev.1.00 Jun 21, 2012

Features

- Low on-resistance $R_{DS(on)} = 0.515~\Omega~typ.~(at~I_D=6~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D Note4	12	Α
Drain peak current	I _{D (pulse)} Note1	24	Α
Body-drain diode reverse drain current	I _{DR}	12	Α
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	24	Α
Avalanche current	I _{AP} Note3	4	Α
Avalanche energy	E _{AR} Note3	0.88	mJ
Channel dissipation	Pch Note2	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C
- 4. Limited by maximum safe operation area

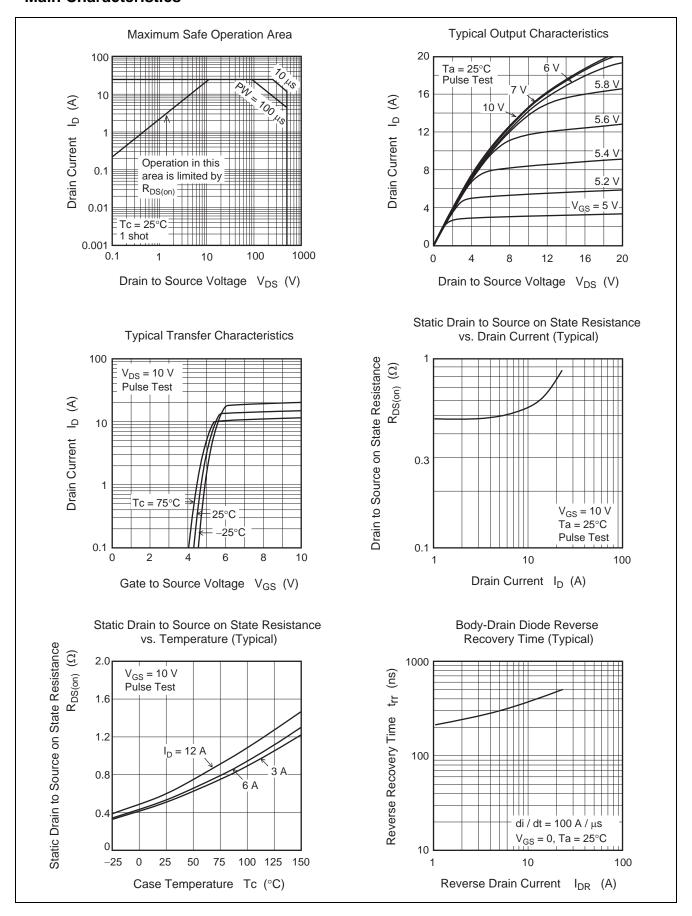
Electrical Characteristics

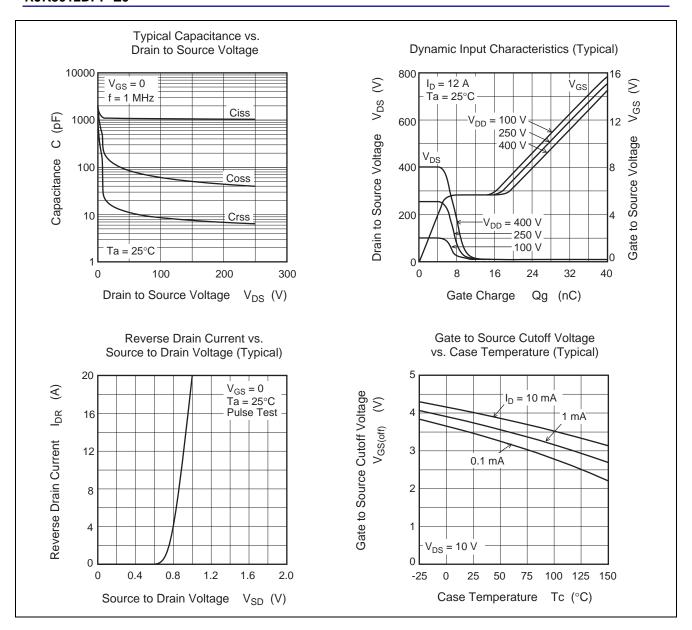
 $(Ta = 25^{\circ}C)$

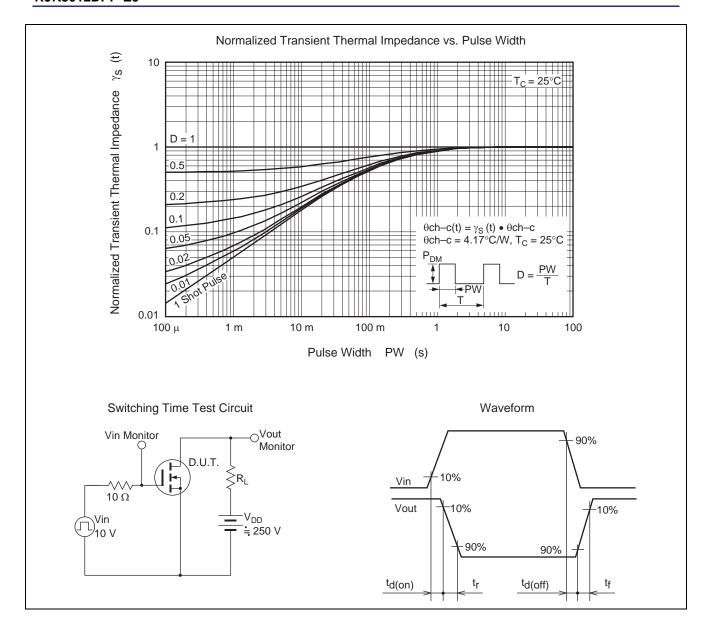
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}		_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	R _{DS(on)}	_	0.515	0.620	Ω	$I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
Input capacitance	Ciss		1100	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	120	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	15	_	pF	
Turn-on delay time	t _{d(on)}	_	30	_	ns	$I_D = 6 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 41.6 \Omega$ $Rg = 10 \Omega$
Rise time	t _r	_	23	_	ns	
Turn-off delay time	$t_{d(off)}$	_	77	_	ns	
Fall time	t _f	_	16	_	ns	
Total gate charge	Qg	_	29	_	nC	$V_{DD} = 400 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 12 \text{ A}$
Gate to source charge	Qgs	_	5.5	_	nC	
Gate to drain charge	Qgd	_	13	_	nC	
Body-drain diode forward voltage	V_{DF}	_	0.89	1.50	V	$I_F = 12 \text{ A}, V_{GS} = 0^{\text{Note5}}$
Body-drain diode reverse recovery time	t _{rr}	_	280	_	ns	$I_F = 12 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu \text{s}$

Notes: 5. Pulse test

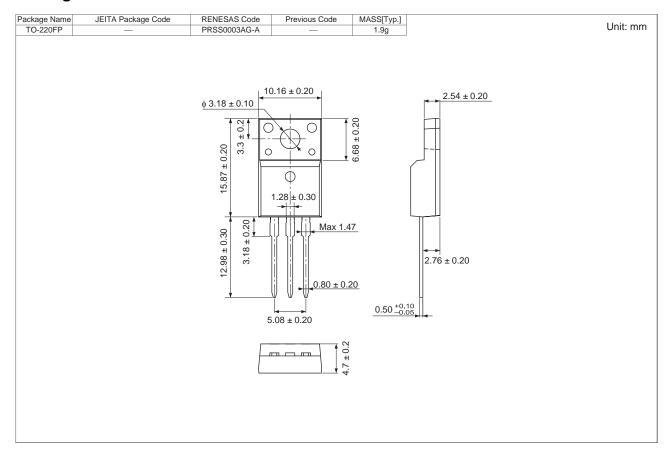
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK5012DPP-E0#T2	1000 pcs	Box (Tube)

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